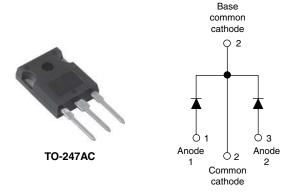


www.vishay.com

Vishay Semiconductors

Ultrafast Rectifier, 2 x 40 A FRED Pt®



| PRODUCT SUMMARY | | | | |
|----------------------------------|----------------|--|--|--|
| Package | TO-247AC | | | |
| I _{F(AV)} | 2 x 40 A | | | |
| V_{R} | 200 V | | | |
| V _F at I _F | 1.02 V | | | |
| t _{rr} typ. | 34 ns | | | |
| T _J max. | 175 °C | | | |
| Diode variation | Common cathode | | | |

FEATURES

- · Ultrafast recovery time
- Low forward voltage drop
- Low leakage current
- 175 °C operating junction temperature
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to

JEDEC-JESD47

• Halogen-free according to IEC 61249-2-21 definition (-N3 only)





COMPLIANT HALOGEN FREE

DESCRIPTIONS/APPLICATIONS

VS-80CPU02... series are the state of the art ultrafast recovery rectifiers designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of welding, SMPS, UPS, DC/DC converters as well as freewheeling diodes in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

| ABSOLUTE MAXIMUM RATINGS | | | | |
|--|-----------------------------------|-------------------------|-------------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | MAX. | UNITS |
| Repetitive peak reverse voltage | V_{RRM} | | 200 | V |
| Average restified forward current | | T _C = 145 °C | 40 | |
| Average rectified forward current total device | I _{F(AV)} | 1 _C = 145 C | 80 | Α |
| Non-repetitive peak surge current per leg | I _{FSM} | T _J = 25 °C | 330 | |
| Operating junction and storage temperatures | T _J , T _{Stg} | | - 65 to 175 | °C |

| ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified) | | | | | | | | | |
|--|-------------------------------------|--|------|--|---|-------|---|-----|----|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS | | | |
| Breakdown voltage, blocking voltage | V _{BR} , V _R | I _R = 100 μA | 200 | - | - | | | | |
| | | I _F = 40 A | | 0.94 | 1.02 | | | | |
| Forward voltage V _F | V | I _F = 40 A, T _J = 150 °C | - | 0.80 | 0.90 | V | | | |
| | ٧F | I _F = 80 A | - | 1.07 | 1.20 | | | | |
| | | I _F = 80 A, T _J = 150 °C | - | 0.97 | 1.08 | | | | |
| Deverage leakers as assument | | $V_R = V_R$ rated | - | - | 5 | | | | |
| Reverse leakage current | I _R | T _J = 150 °C, V _R = V _R rated | | $T_J = 150 ^{\circ}\text{C}, V_R = V_R \text{rated}$ | $T_J = 150 ^{\circ}\text{C}, V_R = V_R \text{ rated}$ | - | - | 500 | μA |
| Junction capacitance | C _T | V _R = 200 V - 120 - | | pF | | | | | |
| Series inductance | L _S | Measured lead to lead 5 mm from package body - 3.5 - nl | | nH | | | | | |



VS-80CPU02-F3, VS-80CPU02-N3

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| DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified) | | | | | | | |
|---|-------------------------|---|---|------|------|------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | | MIN. | TYP. | MAX. | UNITS |
| | | $I_F = 1.0 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$ | | - | 34 | - | |
| Reverse recovery time | t _{rr} | T _J = 25 °C | | - | 33 | - | ns |
| | T _J = 125 °C | $I_F = 40 \text{ A}$ $dI_F/dt = -200 \text{ A/}\mu\text{s}$ $V_R = 200 \text{ V}$ | - | 54 | - | | |
| Peak recovery current I _{RRM} | T _J = 25 °C | | - | 3.4 | - | Α | |
| | T _J = 125 °C | | - | 8 | - | | |
| Reverse recovery charge Q _{rr} | Q _{rr} | T _J = 25 °C | | - | 56 | = | nC |
| neverse recovery charge | Q _{rr} | T _J = 125 °C | | - | 216 | = | 110 |

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | |
|---|-----------------------------------|--|--------------|------|------------|------------------------|
| PARAMETER | SYMBOL | SYMBOL TEST CONDITIONS | | TYP. | MAX. | UNITS |
| Maximum junction and storage temperature range | T _J , T _{Stg} | | - 65 | - | 175 | °C |
| Thermal resistance, junction to case per leg | R _{thJC} | | - | 0.46 | 0.70 | |
| Thermal resistance, junction to ambient per leg | R _{thJA} | Typical socket mount | - | - | 40 | °C/W |
| Thermal resistance, case to heatsink | R _{thCS} | Mounting surface, flat, smooth and greased | - | 0.3 | - | |
| Weight | | | - | 6.0 | - | g |
| vveigni | | | - | 0.21 | - | oz. |
| Mounting torque | | | 6.0 (5.0) | - | 12 (10) | kgf · cm (lbf · in) |
| Marking device | | Case style TO-247AC | | 80CI | PU02 | • |



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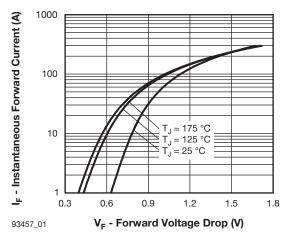


Fig. 1 - Typical Forward Voltage Drop Characteristics

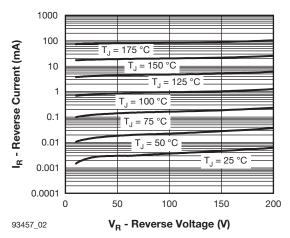


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

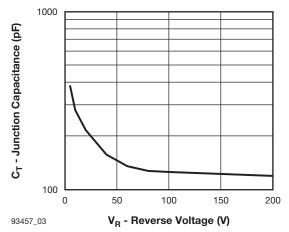


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

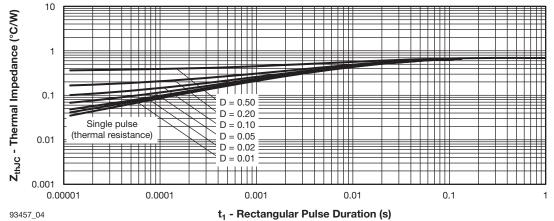


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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180 Allowable Case Temperature (°C) 170 160 DC 150 140 Square wave (D = 0.50)Rated V_R applied 130 120 See note (1) 110 10 60 $I_{F(AV)}$ - Average Forward Current (A) 93457_05

Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

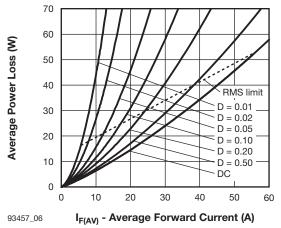


Fig. 6 - Forward Power Loss Characteristics

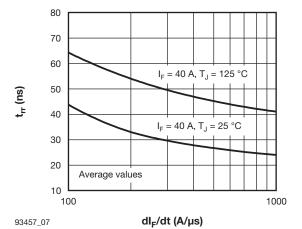


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

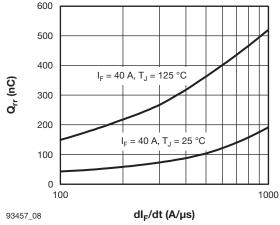


Fig. 8 - Typical Stored Charge vs. dl_F/dt

Note

 $\begin{array}{l} \text{(1)} \ \ \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{th,JC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6)}; \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = \text{Rated } V_R \\ \end{array}$

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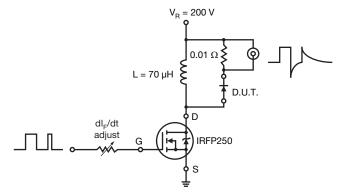
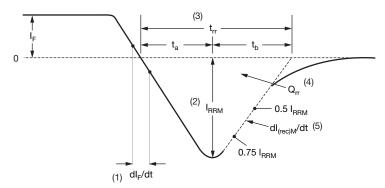


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1) dl_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $\rm t_{rr}$ reverse recovery time measured from zero crossing point of negative going $\rm I_F$ to point where a line passing through 0.75 $\rm I_{RRM}$ and 0.50 $\rm I_{RRM}$ extrapolated to zero current.
- (4) ${\rm Q_{rr}}$ area under curve defined by ${\rm t_{rr}}$ and ${\rm I_{BBM}}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) $dI_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

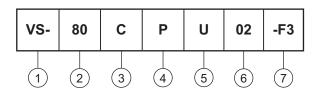
Fig. 9 - Reverse Recovery Waveform and Definitions

VS-80CPU02-F3, VS-80CPU02-N3

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (80 = 80 A)

3 - Circuit configuration:

C = Common cathode

4 - P = TO-247AC

5 - U = Ultrafast rectifier

6 - Voltage rating (02 = 200 V)

7 - Environmental digit:

-F3 = RoHS compliant and totally lead (Pb)-free

-N3 = Halogen-free, RoHS compliant and totally lead (Pb)-free

| ORDERING INFORMATION (Example) | | | | | | |
|--------------------------------|-------------------|------------------------|-------------------------|--|--|--|
| PREFERRED P/N | QUANTITY PER TUBE | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION | | | |
| VS-80CPU02-F3 | 25 | 500 | Antistatic plastic tube | | | |
| VS-80CPU02-N3 | 25 | 500 | Antistatic plastic tube | | | |

| LINKS TO RELATED DOCUMENTS | | | | |
|-------------------------------------|--------------------------|--|--|--|
| Dimensions www.vishay.com/doc?95223 | | | | |
| Part marking | www.vishay.com/doc?95007 | | | |



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- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
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- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



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